Flasher, 18-m Ω Shunt, Extrem Low Power Consumption

Description

The U6432B is an advanced automotive flasher IC which provides lowest stand-by current. Its basic function is equal to the TEMIC flasher IC U6043B but current

Features

- Temperature and voltage compensated frequency
- Warning indication of lamp failure by means of frequency doubling only in direction mode
- Voltage dependence of the car indicator lamps also compensated for lamp failure
- Relay output with high current-carrying capacity and low saturation voltage

consumption and frequency doubling disabling make the outstanding differences.

- Load-dump protection
- Minimum lamp load for flasher operation $\geq 1 \text{ W}$
- Low susceptibility to EMI
- Extremely low stand by current of 10 µA
- Protection according to ISO/TR 7637/1 level 4 with external capacitor (C₂)

Ordering Information

Extended Type Number	Package	Remarks
U6432B	DIP8	
U6432B-FP	SO8	

Block Diagram

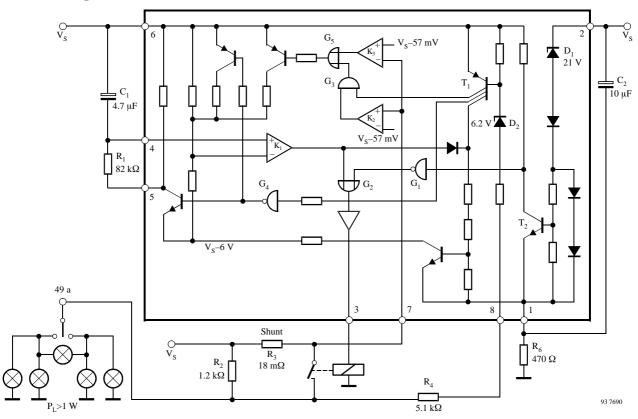
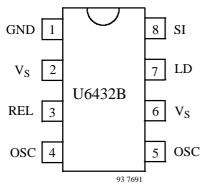


Figure 1. Application as a car flasher

Pin Out



Functional Description

Pin 1, GND

The integrated circuit is protected against damage via resistor R_4 to ground (-31) in the case of battery reversal. An integrated protection circuit together with external resistances R_2 and R_4 limits the current pulses in the IC.

Pin 2, Supply voltage, V_S - Power

The arrangement of the supply connections to Pin 2 (and 6) must be such as ensure that, on the connection printed circuit board (PCB), the resistance of V_S to Pin 6 is lower than that to Pin 2.

Pin 3, Relay control output (driver)

The relay control output is a high-side driver with a low saturation voltage and capable to drive a typical automotive relay with a minimum coil resistance of 60Ω .

Pin 4 and 5 Oscillator

Flashing frequency, f_1 , is determined by the R_1C_1 components as follows (see figure 1):

$$f_1 \approx \frac{1}{R_1 \times C_1 \times 1.5}$$
 Hz

where

$$C_1 \leq 47 \ \mu F$$

R₁ = 6.8 k\Omega to 510 k\Omega

In the case of a lamp outage (see Pin 7) the oscillator frequency is switched to the lamp outage frequency f_2 with $f_2 \approx 2.2 f_1$.

Duty cycle in normal flashing mode: 50% Duty cycle in lamp outage mode: 40% (bright phase)

Pin 6, Supply voltage, Sense

For accurate monitoring via the shunt resistor, a minimized layer resistance from point $V_S\,/$ shunt to Pin 6 is recommended.

Pin Description

Pin	Symbol	Function
1	GND	IC ground
2	VS	Supply voltage
3	REL	Relay driver
4	OSC	Oscillator
5	OSC	Oscillator
6	VS	Supply voltage
7	LD	Lamp failure detection
8	SI	Start input (49a)

Pin 7, Control signal threshold 1 (49-mV comparator)

The detection point for lamp failure can be calculated from the control signal threshold, typically 49 mV with $V_S = 12$ V. With a measuring resistance of $R_3 = 18$ m Ω , the frequency changeover is reached at a lamp load of 21 W + 11.4 W. The variation of the control signal threshold supply voltage takes into account the PTC characteristic of filament lamps.

Control Signal Threshold 2 (15-mV Comparator)

A voltage drop at the shunt resistor R_3 between 49 mV and 15 mV let the flasher work in frequency doubling mode.

If the voltage drop falls of $V_{R3MAX} = 15 \text{ mV}$ the frequency doubling is disabled.

This can be achieved either with a switch which by-passes the shunt resistor (e.g., a special hazard warning switch) or with a small lamp load.

Flasher operation starts with a lamp load of $P_L \ge 1$ W.

Pin 8, Start input

Start condition for flashing:

Voltage at Pin 8 (see block diagram)

 $V_8 \, \leq \, V_S - (V_{BE(T1)} + V_{Z(D2)})$

Condition for stand-by:

The resistor R_2 between Vs and Pin 8 gives an extrem low stand-by current ($I_S \le 10 \ \mu A$). The leakage current depends on the pull-up resistor R2 according the following formula:

 $I_{Leak} \approx (V_{BE(T1)} + V_{Z(D2)})/R2$

Application Hint

In order to achieve a high level immunity against "electrical interference by conduction and coupling" according to ISO/TR 7637/1 test level 4 an electrolythic capacitor $C_2 = 10 \ \mu F (25 \ V)$ between Pin 1 and 2 – mounted close to the IC – is highly recommended.

Absolute Maximum Ratings

Reference point Pin 1

Parameters			Symbol	Value	Unit
Supply voltage	Pins 2 a	nd 6	Vs	18	V
Surge forward current	$t_p = 0.1 \text{ ms}$ F $t_p = 300 \text{ ms}$ F $t_p = 300 \text{ ms}$ F		I _{FSM}	1.5 1.0 30.0	A A mA
Output current	Pin 3		IO	0.3	А
Power dissipation	$T_{amb} = 95^{\circ}C$ $T_{amb} = 60^{\circ}C$	DIP8 SO8 DIP8 SO8	P _{tot}	420 340 690 560	mW
Junction temperature			Tj	150	°C
Ambient temperature ran	ge		T _{amb}	-40 to $+105$	°C
Storage temperature rang	je		T _{stg}	-55 to +150	°C

Electrical Characteristics

 $T_{amb} = 25$ °C; typical values under normal operation in application circuit figure 1, $V_S = 12$ V (Pins 2 and 6); reference point ground (-31), unless otherwise specified.

Parameters	Test Conditions / Pins	Symbol	Min.	Тур.	Max.	Unit
Supply voltage range	Pins 2 and 6	VS	9		16.5	V
Supply current, dark phase	Pins 2 and 6	IS		4.5	8	mA
Supply current, stand-by	Pins 2 and 6	IS			10	μΑ
Supply current, bright phase	Pins 2 and 6	I _S		7.0	11	mA
Relay output, saturation voltage	$I_{O} = 150 \text{ mA},$ V_{S} = 9 V Pin 3	Vo			1.0	V
Relay output reverse current	Pin 3	IO			0.1	mA
Relay coil resistance		R _L	60			Ω
Start delay	First bright phase	t _{on}			10	ms
Frequency determining resistor		R ₁	6.8		510	kΩ
Frequency determining capacitor		C ₁			47	μF
Frequency tolerance	Normal flashing, basic frequency f_1 not including the tolerances of the exter- nal components R_1 and C_1	Δf_1	-5		+5	%
Bright period	Basic frequency $f_{1,}$ V _S = 9-15 V	Δf_1	47		53	%
Bright period	Control frequency f_{2} , $V_S = 9-15 V$	Δf_2	37		45	%
Frequency increase	Lamp failure, $V_S = 9-15 V$	f ₂	$2.15 \times f_1$		$2.3 \times f_1$	Hz

U6432B

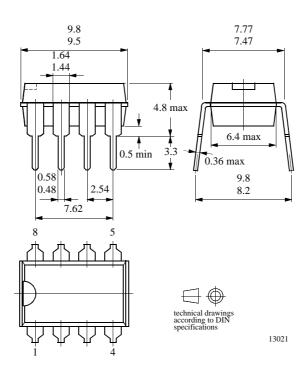


Parameters	Test Conditions / Pins	Symbol	Min.	Тур.	Max.	Unit
Control signal threshold 1		V _{R3}	50 43 47	53 45 49	57 47 51	mV
Control signal threshold 2		V _{R3}			15	mV
Lamp load		PL	1			W

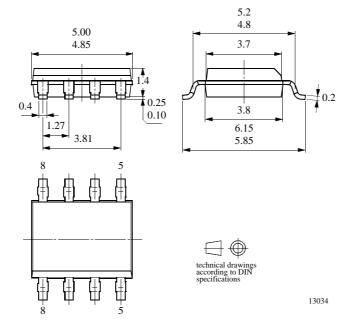


Package Information

Package DIP8 Dimensions in mm



Package SO8 Dimensions in mm



Ozone Depleting Substances Policy Statement

It is the policy of TEMIC TELEFUNKEN microelectronic GmbH to

- 1. Meet all present and future national and international statutory requirements.
- 2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

TEMIC TELEFUNKEN microelectronic GmbH semiconductor division has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

- 1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
- 2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
- 3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

TEMIC can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design and may do so without further notice. Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use TEMIC products for any unintended or unauthorized application, the buyer shall indemnify TEMIC against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

TEMIC TELEFUNKEN microelectronic GmbH, P.O.B. 3535, D-74025 Heilbronn, Germany Telephone: 49 (0)7131 67 2831, Fax number: 49 (0)7131 67 2423